# 37. Electrical Characteristics

All typical values are measured at  $T = 25^{\circ}C$  unless other temperature condition is given. All minimum and maximum values are valid across operating temperature and voltage unless other conditions are given.

Note: For devices that are not available yet, preliminary values in this datasheet are based on simulations, and/or characterization of similar AVR XMEGA microcontrollers. After the device is characterized the final values will be available, hence existing values can change. Missing minimum and maximum values will be available after the device is characterized.

# 37.1 ATxmega64A1U

# 37.1.1 Absolute Maximum Ratings

Stresses beyond those listed in Table 37-1 on page 74 under may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### Table 37-1. Absolute maximum ratings.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units	
V <sub>CC</sub>	Power supply voltage		-0.3		4	V	
I <sub>VCC</sub>	Current into a $V_{CC}$ pin				200	200 mA	
I <sub>GND</sub>	Current out of a Gnd pin				200		
V <sub>PIN</sub>	Pin voltage with respect to Gnd and $\mathrm{V}_{\mathrm{CC}}$		-0.5		V <sub>CC</sub> +0.5	V	
I <sub>PIN</sub>	I/O pin sink/source current		-25		25	mA	
T <sub>A</sub>	Storage temperature		-65		150	°C	
Tj	Junction temperature				150	C	

# 37.1.2 General Operating Ratings

The device must operate within the ratings listed in Table 37-2 in order for all other electrical characteristics and typical characteristics of the device to be valid.

## Table 37-2. General operating conditions.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units	
V <sub>CC</sub>	Power supply voltage		1.60		3.6	V	
AV <sub>CC</sub>	Analog supply voltage		1.60		3.6	V	
T <sub>A</sub>	Temperature range		-40		85	°C	
Tj	Junction temperature		-40		105		

# 37.1.5 I/O Pin Characteristics

The I/O pins complies with the JEDEC LVTTL and LVCMOS specification and the high- and low level input and output voltage limits reflect or exceed this specification.

Table 37-7.	I/O pin	characteristics.
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Symbol	Parameter	Condition		Min.	Тур.	Max.	Units	
I <sub>OH</sub> <sup>(1)</sup> / I <sub>OL</sub> <sup>(2)</sup>	I/O pin source/sink current			-20		20	mA	
V <sub>IH</sub>		V <sub>CC</sub> = 2.7 - 3.6V		2		V <sub>CC</sub> +0.3		
	High level input voltage	V <sub>CC</sub> = 2.0 - 2.7V		0.7*V <sub>CC</sub>		V <sub>CC</sub> +0.3		
		V <sub>CC</sub> = 1.6 - 2.0V		0.7*V <sub>CC</sub>		V <sub>CC</sub> +0.3		
V <sub>IL</sub>	Low level input voltage	V <sub>CC</sub> = 2.7- 3.6V		-0.3		0.3*V <sub>CC</sub>		
		V <sub>CC</sub> = 2.0 - 2.7V		-0.3		0.3*V <sub>CC</sub>		
		V <sub>CC</sub> = 1.6 - 2.0V		-0.3		0.3*V <sub>CC</sub>		
V <sub>OH</sub>	High level output voltage	V <sub>CC</sub> = 3.0 - 3.6V	I <sub>OH</sub> = -2mA	2.4	0.94*V <sub>CC</sub>		V	
		V <sub>CC</sub> = 2.3 - 2.7V	I <sub>OH</sub> = -1mA	2.0	0.96*V <sub>CC</sub>			
			I <sub>OH</sub> = -2mA	1.7	0.92*V <sub>CC</sub>			
		V <sub>CC</sub> = 3.3V	I <sub>OH</sub> = -8mA	2.6	2.9			
		V <sub>CC</sub> = 3.0V	I <sub>OH</sub> = -6mA	2.1	2.6			
		V <sub>CC</sub> = 1.8V	I <sub>OH</sub> = -2mA	1.4	1.6			
	Low level output voltage	V <sub>CC</sub> = 3.0 - 3.6V	I <sub>OL</sub> = 2mA		0.05*V <sub>CC</sub>	0.4		
V <sub>OL</sub>		V <sub>CC</sub> = 2.3 - 2.7V	I <sub>OL</sub> = 1mA		0.03*V <sub>CC</sub>	0.4		
			I <sub>OL</sub> = 2mA		0.06*V <sub>CC</sub>	0.7		
		V <sub>CC</sub> = 3.3V	I <sub>OL</sub> = 15mA		0.4	0.76		
		V <sub>CC</sub> = 3.0V	I <sub>OL</sub> = 10mA		0.3	0.64		
		V <sub>CC</sub> = 1.8V	I <sub>OL</sub> = 5mA		0.3	0.46		
I <sub>IN</sub>	Input leakage current				<0.001	0.1	μA	
R <sub>P</sub>	I/O pin Pull/Buss keeper resistor				25		ko	
R <sub>RST</sub>	Reset pin pull-up resistor				25		K12	
t <sub>r</sub>	Pad rise time	Nolood			4.0		ns	
		100 1080	slew rate limitation		7.0			

1. The sum of all  $I_{OH}$  for PORTA, PORTC, PORTD, PORTF, PORTH, PORTJ, PORTK must for each port not exceed 200mA. The sum of all  $I_{OH}$  for PORTB must not exceed 100mA. The sum of all  $I_{OH}$  for PORTQ, PORTR and PDI must not exceed 100mA. Notes:

The sum of all  $I_{OL}$  for PORTA, PORTC, PORTD, PORTF, PORTH, PORTJ, PORTK must for each port not exceed 200mA. The sum of all  $I_{OL}$  for PORTB must not exceed 100mA. The sum of all  $I_{OL}$  for PORTQ, PORTR and PDI must not exceed 100mA. 2.

